



Is Now Part of



**ON Semiconductor®**

To learn more about ON Semiconductor, please visit our website at  
[www.onsemi.com](http://www.onsemi.com)

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at [www.onsemi.com](http://www.onsemi.com). Please email any questions regarding the system integration to [Fairchild\\_questions@onsemi.com](mailto:Fairchild_questions@onsemi.com).

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.



September 2015

# MOC3061M, MOC3062M, MOC3063M, MOC3162M, MOC3163M 6-Pin DIP Zero-Cross Triac Driver Optocoupler (600 Volt Peak)

## Features

- Simplifies Logic Control of 115/240 VAC Power
- Zero Voltage Crossing to Minimize Conducted and Radiated Line Noise
- 600 V Peak Blocking Voltage
- Superior Static dv/dt
  - 600 V/ $\mu$ s (MOC306xM)
  - 1000 V/ $\mu$ s (MOC316xM)
- Safety and Regulatory Approvals
  - UL1577, 4,170 VAC<sub>RMS</sub> for 1 Minute
  - DIN EN/IEC60747-5-5

## Description

The MOC306XM and MOC316XM devices consist of a GaAs infrared emitting diode optically coupled to a monolithic silicon detector performing the function of a zero voltage crossing bilateral triac driver.

They are designed for use with a triac in the interface of logic systems to equipment powered from 115/240 VAC lines, such as solid-state relays, industrial controls, motors, solenoids and consumer appliances, etc.

## Applications

- Solenoid/Valve Controls
- Static Power Switches
- Temperature Controls
- AC Motor Starters
- Lighting Controls
- AC Motor Drives
- E.M. Contactors
- Solid State Relays

## Schematic

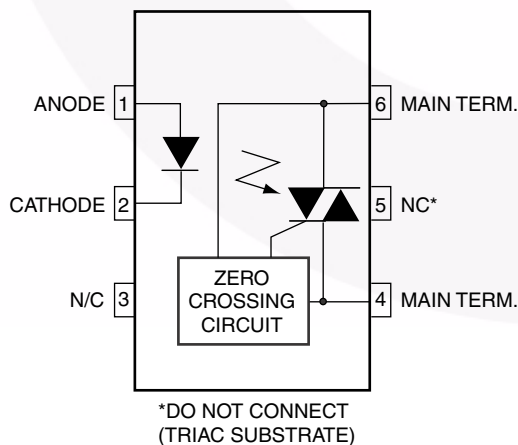


Figure 1. Schematic

## Package Outlines

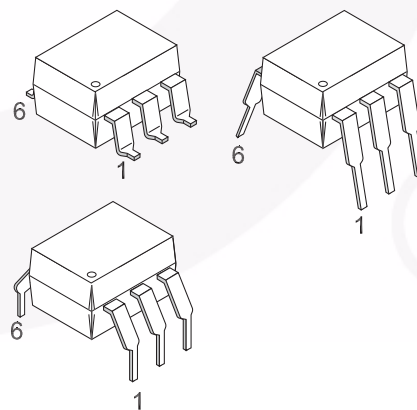


Figure 2. Package Outlines

MOC306XM, MOC316XM — 6-Pin DIP Zero-Cross Triac Driver Optocoupler (600 Volt Peak)

## Safety and Insulation Ratings

As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for “safe electrical insulation” only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

| Parameter   |                        | Characteristics |
|---|------------------------|-----------------|
| Installation Classifications per DIN VDE 0110/1.89 Table 1, For Rated Mains Voltage | < 150 V <sub>RMS</sub> | I-IV            |
|   | < 300 V <sub>RMS</sub> | I-IV            |
| Climatic Classification   |                        | 40/85/21        |
| Pollution Degree (DIN VDE 0110/1.89)  |                        | 2               |
| Comparative Tracking Index  |                        | 175             |

| Symbol            | Parameter  | Value             | Unit              |
|-------------------|--|-------------------|-------------------|
| V <sub>PR</sub>   | Input-to-Output Test Voltage, Method A, V <sub>IORM</sub> × 1.6 = V <sub>PR</sub> , Type and Sample Test with t <sub>m</sub> = 10 s, Partial Discharge < 5 pC  | 1360              | V <sub>peak</sub> |
|                   | Input-to-Output Test Voltage, Method B, V <sub>IORM</sub> × 1.875 = V <sub>PR</sub> , 100% Production Test with t <sub>m</sub> = 1 s, Partial Discharge < 5 pC | 1594              | V <sub>peak</sub> |
| V <sub>IORM</sub> | Maximum Working Insulation Voltage   | 850               | V <sub>peak</sub> |
| V <sub>IOTM</sub> | Highest Allowable Over-Voltage   | 6000              | V <sub>peak</sub> |
|                   | External Creepage  | ≥ 7               | mm                |
|                   | External Clearance   | ≥ 7               | mm                |
|                   | External Clearance (for Option TV, 0.4" Lead Spacing)  | ≥ 10              | mm                |
| DTI               | Distance Through Insulation (Insulation Thickness)   | ≥ 0.5             | mm                |
| R <sub>IO</sub>   | Insulation Resistance at T <sub>S</sub> , V <sub>IO</sub> = 500 V  | > 10 <sup>9</sup> | Ω                 |

## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.  $T_A = 25^\circ\text{C}$  unless otherwise specified.

| Symbol              | Parameters  | Device | Value                 | Unit                 |
|---------------------|---|--------|-----------------------|----------------------|
| <b>TOTAL DEVICE</b> |   |        |                       |                      |
| $T_{STG}$           | Storage Temperature   | All    | -40 to +150           | $^\circ\text{C}$     |
| $T_{OPR}$           | Operating Temperature   | All    | -40 to +85            | $^\circ\text{C}$     |
| $T_J$               | Junction Temperature Range  | All    | -40 to +100           | $^\circ\text{C}$     |
| $T_{SOL}$           | Lead Solder Temperature   | All    | 260 for<br>10 seconds | $^\circ\text{C}$     |
| $P_D$               | Total Device Power Dissipation at $25^\circ\text{C}$ Ambient        | All    | 250                   | mW                   |
|                     | Derate Above $25^\circ\text{C}$                                     |        | 2.94                  | mW/ $^\circ\text{C}$ |
| <b>EMITTER</b>      |   |        |                       |                      |
| $I_F$               | Continuous Forward Current  | All    | 60                    | mA                   |
| $V_R$               | Reverse Voltage   | All    | 6                     | V                    |
| $P_D$               | Total Power Dissipation at $25^\circ\text{C}$ Ambient               | All    | 120                   | mW                   |
|                     | Derate Above $25^\circ\text{C}$                                     |        | 1.41                  | mW/ $^\circ\text{C}$ |
| <b>DETECTOR</b>     |   |        |                       |                      |
| $V_{DRM}$           | Off-State Output Terminal Voltage                                   | All    | 600                   | V                    |
| $I_{TSM}$           | Peak Non-Repetitive Surge Current<br>(Single Cycle 60 Hz Sine Wave) | All    | 1                     | A                    |
| $P_D$               | Total Power Dissipation at $25^\circ\text{C}$ Ambient               | All    | 150                   | mW                   |
|                     | Derate Above $25^\circ\text{C}$                                     |        | 1.76                  | mW/ $^\circ\text{C}$ |

## Electrical Characteristics

$T_A = 25^\circ\text{C}$  unless otherwise specified.

### Individual Component Characteristics

| Symbol            | Parameters                                 | Test Conditions                                   | Device   | Min. | Typ.  | Max. | Unit             |
|-------------------|--|---|----------|------|-------|------|------------------|
| <b>EMITTER</b>    |  |   |          |      |       |      |                  |
| $V_F$             | Input Forward Voltage                      | $I_F = 30\text{ mA}$                              | All      |      | 1.3   | 1.5  | V                |
| $I_R$             | Reverse Leakage Current                    | $V_R = 6\text{ V}$                                | All      |      | 0.005 | 100  | $\mu\text{A}$    |
| <b>DETECTOR</b>   |  |   |          |      |       |      |                  |
| $I_{\text{DRM1}}$ | Peak Blocking Current, Either Direction    | $V_{\text{DRM}} = 600\text{ V}$ , $I_F = 0^{(1)}$ | MOC306XM |      | 10    | 500  | nA               |
|                   |  |   | MOC316XM |      | 10    | 100  |                  |
| dv/dt             | Critical Rate of Rise of Off-State Voltage | $I_F = 0$ (Figure 11) <sup>(2)</sup>              | MOC306XM | 600  | 1500  |      | V/ $\mu\text{s}$ |
|                   |  |   | MOC316XM | 1000 |       |      |                  |

### Transfer Characteristics

| Symbol          | DC Characteristics                           | Test Conditions  | Device   | Min. | Typ. | Max. | Unit          |
|-----------------|--|--|----------|------|------|------|---------------|
| $I_{\text{FT}}$ | LED Trigger Current (Rated $I_{\text{FT}}$ ) | Main Terminal Voltage = $3\text{ V}^{(3)}$                                 | MOC3061M |      |      | 15   | mA            |
|                 |  |  | MOC3062M |      |      | 10   |               |
|                 |  |  | MOC3162M |      |      | 10   |               |
|                 |  |  | MOC3063M |      |      | 5    |               |
| $V_{\text{TM}}$ | Peak On-State Voltage, Either Direction      | $I_{\text{TM}} = 100\text{ mA peak}$ , $I_F = \text{rated } I_{\text{FT}}$ | All      |      | 1.8  | 3.0  | V             |
| $I_{\text{H}}$  | Holding Current, Either Direction            |  | All      |      | 500  |      | $\mu\text{A}$ |

### Zero Crossing Characteristics

| Symbol            | Characteristics   | Test Conditions   | Device   | Min. | Typ. | Max. | Unit |
|-------------------|---|---|----------|------|------|------|------|
| $V_{\text{INH}}$  | Inhibit Voltage (MT1-MT2 voltage above which device will not trigger) | $I_F = \text{rated } I_{\text{FT}}$   | MOC3061M |      | 12   | 20   | V    |
|                   |   |   | MOC3062M |      |      |      |      |
|                   |   |   | MOC3063M |      |      |      |      |
|                   |   |   | MOC3162M |      | 12   | 15   |      |
| MOC3163M          |   |   |          |      |      |      |      |
| $I_{\text{DRM2}}$ | Leakage in Inhibited State  | $I_F = \text{rated } I_{\text{FT}}$ , $\text{DRM} = 600\text{ V}$ , off-state | All      |      |      | 2    | mA   |

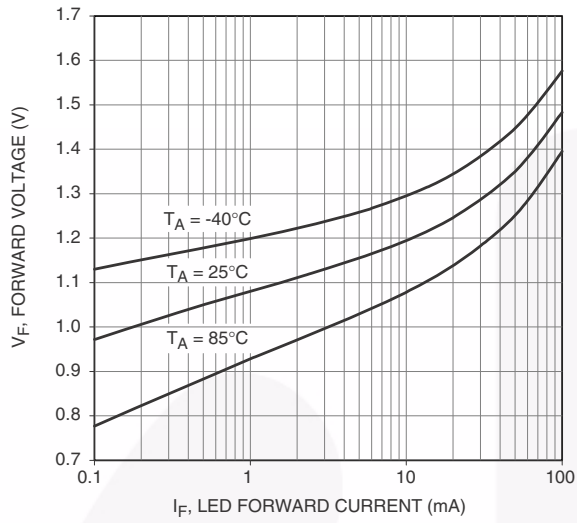
### Isolation Characteristics

| Symbol           | Parameter                        | Test Conditions                             | Min. | Typ.      | Max. | Unit               |
|------------------|----------------------------------|---|------|-----------|------|--------------------|
| $V_{\text{ISO}}$ | Isolation Voltage <sup>(4)</sup> | $f = 60\text{ Hz}$ , $t = 1\text{ Minute}$  | 4170 |           |      | $V_{\text{ACRMS}}$ |
| $R_{\text{ISO}}$ | Isolation Resistance             | $V_{\text{I-O}} = 500\text{ V}_{\text{DC}}$ |      | $10^{11}$ |      | $\Omega$           |
| $C_{\text{ISO}}$ | Isolation Capacitance            | $V = 0\text{ V}$ , $f = 1\text{ MHz}$       |      | 0.2       |      | pF                 |

#### Notes:

- Test voltage must be applied within dv/dt rating.
- This is static dv/dt. See Figure 11 for test circuit. Commutating dv/dt is a function of the load-driving thyristor(s) only.
- All devices are guaranteed to trigger at an  $I_F$  value less than or equal to max  $I_{\text{FT}}$ . Therefore, recommended operating  $I_F$  lies between max  $I_{\text{FT}}$  (15 mA for MOC3061M, 10 mA for MOC3062M and MOC3162M, 5 mA for MOC3063M and MOC3163M) and absolute maximum  $I_F$  (60 mA).
- Isolation voltage,  $V_{\text{ISO}}$ , is an internal device dielectric breakdown rating. For this test, pins 1 and 2 are common, and pins 4, 5 and 6 are common.

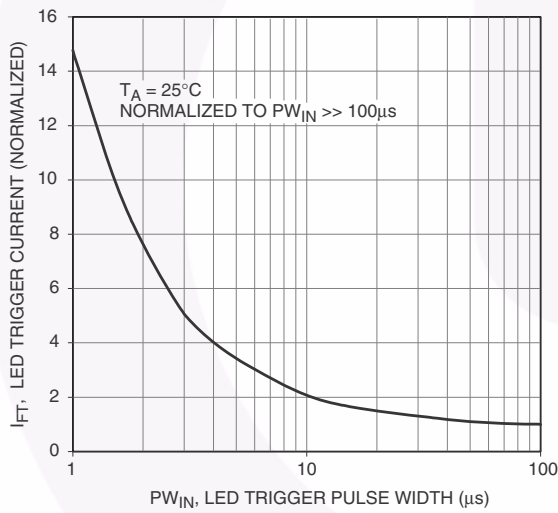
## Typical Performance Curves



**Figure 3. LED Forward Voltage vs. Forward Current**



**Figure 4. Trigger Current vs. Temperature**



**Figure 5. LED Current Required to Trigger vs. LED Pulse Width**



**Figure 6. Leakage Current,  $I_{DRM}$  vs. Temperature**

Typical Performance Curves (Continued)



Figure 7.  $I_{DRM2}$ , Leakage in Inhibit State vs. Temperature



Figure 8. On-State Characteristics



Figure 9.  $I_H$ , Holding Current vs. Temperature



Figure 10. Inhibit Voltage vs. Temperature

1. 100x scope probes are used, to allow high speeds and voltages.
2. The worst-case condition for static  $dv/dt$  is established by triggering the D.U.T. with a normal LED input current, then removing the current. The variable vernier resistor combined with various capacitor combinations allows the  $dv/dt$  to be gradually increased until the D.U.T. continues to trigger in response to the applied voltage pulse, even after the LED current has been removed. The  $dv/dt$  is then decreased until the D.U.T. stops triggering.  $t_{RC}$  is measured at this point and recorded.



ALL COMPONENTS ARE NON-INDUCTIVE UNLESS SHOWN  
**Figure 11. Circuit for Static  $\frac{dv}{dt}$  Measurement of Power Thyristors**

## Basic Applications

Typical circuit for use when hot line switching is required. In this circuit the "hot" side of the line is switched and the load connected to the cold or neutral side. The load may be connected to either the neutral or hot line.

$R_{in}$  is calculated so that  $I_F$  is equal to the rated  $I_{FT}$  of the part, 15mA for the MOC3061M, 10mA for the MOC3062M, or 5mA for the MOC3063M. The 39Ω resistor and 0.01μF capacitor are for snubbing of the triac and is often, but not always, necessary depending upon the particular triac and load used.



**Figure 12. Hot-Line Switching Application Circuit**

Suggested method of firing two, back-to-back SCR's with a Fairchild triac driver. Diodes can be 1N4001; resistors, R1 and R2, are optional 330Ω.

### Note:

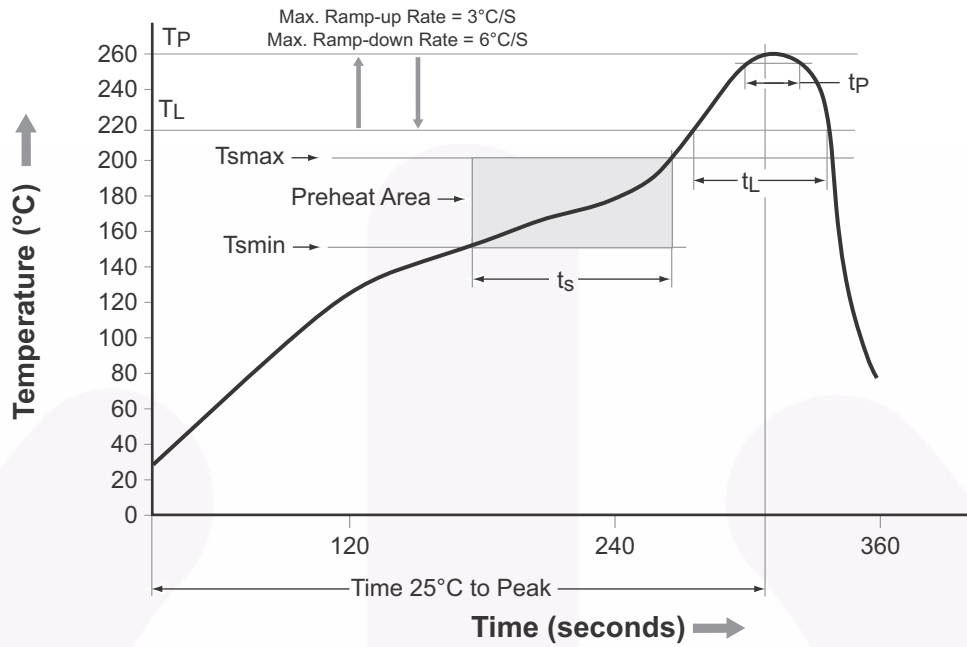
This optoisolator should not be used to drive a load directly. It is intended to be a trigger device only.



**Figure 13. Inverse-Parallel SCR Driver Circuit**



### Reflow Profile



| Profile Feature   | Pb-Free Assembly Profile  |
|---|---------------------------|
| Temperature Minimum (T <sub>smin</sub> )                              | 150°C                     |
| Temperature Maximum (T <sub>smax</sub> )                              | 200°C                     |
| Time (t <sub>s</sub> ) from (T <sub>smin</sub> to T <sub>smax</sub> ) | 60 seconds to 120 seconds |
| Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )                      | 3°C/second maximum        |
| Liquidous Temperature (T <sub>L</sub> )                               | 217°C                     |
| Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )             | 60 seconds to 150 seconds |
| Peak Body Package Temperature   | 260°C +0°C / -5°C         |
| Time (t <sub>p</sub> ) within 5°C of 260°C                            | 30 seconds                |
| Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )                    | 6°C/second maximum        |
| Time 25°C to Peak Temperature   | 8 minutes maximum         |

Figure 14. Reflow Profile

## Ordering Information<sup>(5)</sup>

| Part Number  | Package  | Packing Method             |
|--------------|--|----------------------------|
| MOC3061M     | DIP 6-Pin  | Tube (50 Units)            |
| MOC3061SM    | SMT 6-Pin (Lead Bend)                                    | Tube (50 Units)            |
| MOC3061SR2M  | SMT 6-Pin (Lead Bend)                                    | Tape and Reel (1000 Units) |
| MOC3061VM    | DIP 6-Pin, DIN EN/IEC60747-5-5 Option                    | Tube (50 Units)            |
| MOC3061SVM   | SMT 6-Pin (Lead Bend), DIN EN/IEC60747-5-5 Option        | Tube (50 Units)            |
| MOC3061SR2VM | SMT 6-Pin (Lead Bend), DIN EN/IEC60747-5-5 Option        | Tape and Reel (1000 Units) |
| MOC3061TVM   | DIP 6-Pin, 0.4" Lead Spacing, DIN EN/IEC60747-5-5 Option | Tube (50 Units)            |

**Note:**

5. The product orderable part number system listed in this table also applies to the MOC3062M, MOC3063M, MOC3162M, and MOC3163M product families.

## Marking Information



Figure 15. Top Mark

| Top Mark Definitions |   |
|----------------------|---|
| 1                    | Fairchild Logo  |
| 2                    | Device Number   |
| 3                    | DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option) |
| 4                    | One-Digit Year Code, e.g., '5'  |
| 5                    | Two-Digit Work Week, Ranging from '01' to '53'                                  |
| 6                    | Assembly Package Code   |



NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION
- D) DRAWING FILENAME AND REVISION: MKT-N06BREV4.





LAND PATTERN RECOMMENDATION



NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION
- D) DRAWING FILENAME AND REVISION : MKT-N06CREV4.





NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION
- D) DRAWING FILENAME AND REVISION: MKT-N06Drev4



ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## PUBLICATION ORDERING INFORMATION

### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor  
19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA  
**Phone:** 303-675-2175 or 800-344-3860 Toll Free USA/Canada  
**Fax:** 303-675-2176 or 800-344-3867 Toll Free USA/Canada  
**Email:** [orderlit@onsemi.com](mailto:orderlit@onsemi.com)

**N. American Technical Support:** 800-282-9855 Toll Free  
USA/Canada  
**Europe, Middle East and Africa Technical Support:**  
Phone: 421 33 790 2910  
**Japan Customer Focus Center**  
Phone: 81-3-5817-1050

**ON Semiconductor Website:** [www.onsemi.com](http://www.onsemi.com)  
**Order Literature:** <http://www.onsemi.com/orderlit>  
For additional information, please contact your local  
Sales Representative

# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[ON Semiconductor:](#)

[MOC3061TVM](#) [MOC3061SVM](#) [MOC3061M](#) [MOC3061SR2M](#) [MOC3061VM](#) [MOC3061SM](#) [MOC3061SR2VM](#)

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «**JONHON**», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «**FORSTAR**».



## JONHON

«**JONHON**» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«**FORSTAR**» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: [ocean@oceanchips.ru](mailto:ocean@oceanchips.ru)

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А